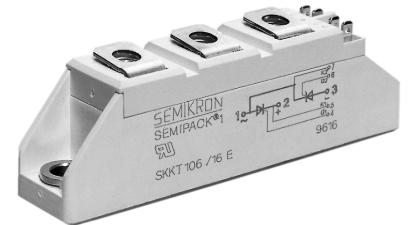


V _{RSM}	V _{RDM}	(dv/dt) _{cr}	I _{TRMS} (maximum value for continuous operation)			
			95 A			
V	V	V/μs	I _{TAV} (sin. 180; T _{case} = 74°C)			
			60 A			
500	400	500	–	–	SKKH 56/04 D	–
700	600	500	SKKT 56/06 D	SKKT 57/06 D	SKKH 56/06 D	SKKH 57/06 D
900	800	500	SKKT 56/08 D	SKKT 57/08 D ¹⁾	SKKH 56/08 D	SKKH 57/08 D
1300	1200	1000	SKKT 56/12 E	SKKT 57/12 E ¹⁾	SKKH 56/12 E	SKKH 57/12 E
1500	1400	1000	SKKT 56/14 E	SKKT 57/14 E ¹⁾	SKKH 56/14 E	SKKH 57/14 E
1700	1600	1000	SKKT 56/16 E	SKKT 57/16 E ¹⁾	SKKH 56/16 E	SKKH 57/16 E
1900	1800	1000	SKKT 56/18 E	SKKT 57/18 E ¹⁾	SKKH 56/18 E	SKKH 57/18 E
2100	2000	1000	SKKT 56/20 E	SKKT 57/20 E ¹⁾	–	SKKH 57/20 E
2300	2200	1000	SKKT 56/22 E	SKKT 57/22 E ¹⁾	–	SKKH 57/22 E

SEMIPACK® 1 Thyristor / Diode Modules

SKKT 56 **SKKH 56**
SKKT 57 **SKKH 57**
SKKT 57B



Symbol	Conditions	SKKT 56 SKKH 56	SKKT 57 SKKT 57B SKKH 57	Units
I _{TAV}	sin. 180; T _{case} = 74 °C T _{case} = 80 °C		60 55	A A
I _D	B2/B6 T _{amb} = 45 °C; P 3/180 T _{amb} = 35 °C; P 3/180 F		57 / 68 100 / 130	A A
I _{RMS}	W1/W3 T _{amb} = 35 °C; P 3/180 F		130 / 3 x 100	A
I _{TSM}	T _{vj} = 25 °C; 10 ms T _{vj} = 125 °C; 10 ms		1 500 1 250	A A
i ² t	T _{vj} = 25 °C; 8,3 ... 10 ms T _{vj} = 125 °C; 8,3 ... 10 ms		11 000 8 000	A ² s A ² s
t _{gd}	T _{vj} = 25 °C; I _G = 1 A; di _G /dt = 1 A/μs		1	μs
t _{gr}	V _D = 0,67 · V _{DRM}		2	μs
(di/dt) _{cr}	T _{vj} = 125 °C		150	A/μs
t _q	T _{vj} = 125 °C		typ. 80	μs
I _H	T _{vj} = 25 °C; typ./max.		150 / 250	mA
I _L	T _{vj} = 25 °C; R _G = 33 Ω; typ./max.		300 / 600	mA
V _T	T _{vj} = 25 °C; I _T = 200 A		max. 1,65	V
V _{T(TO)}	T _{vj} = 125 °C		0,9	V
r _T	T _{vj} = 125 °C		3,5	mΩ
I _{DD} ; I _{RD}	T _{vj} = 125 °C; V _{RD} = V _{RDM} V _{DD} = V _{DRM}		max. 15 ³⁾	mA
V _{GT}	T _{vj} = 25 °C; d.c.		3	V
I _{GT}	T _{vj} = 25 °C; d.c.		150	mA
V _{GD}	T _{vj} = 125 °C; d.c.		0,25	V
I _{GD}	T _{vj} = 125 °C; d.c.		6	mA
R _{thjc}	cont. } sin. 180 } per thyristor / rec. 120 } per module		0,57 / 0,29 0,60 / 0,30 0,64 / 0,32	°C/W °C/W °C/W
R _{thch}			0,2 / 0,1	°C/W
T _{vj}			– 40 ... + 125	°C
T _{stg}			– 40 ... + 125	°C
V _{isol}	a. c. 50 Hz; r.m.s.; 1 s/1 min		3600 / 3000	V~
M ₁	to heatsink } to terminals } SI (US) units		5 (44 lb. in.) ± 15 % ²⁾	Nm
M ₂			3 (26 lb. in.) ± 15 %	Nm
a			5 · 9,81	m/s ²
w	approx.		95	g
Case	→ page B 1 – 95	SKKT 56: A 5 SKKH 56: A 6	SKKT 57: A 46 SKKT 57B: A 48 SKKH 57: A 47	



SKKT 56 **SKKH 56**



SKKT 57 **SKKH 57**
SKKT 57B

Features

- Heat transfer through aluminium oxide ceramic isolated metal baseplate
- Hard soldered joints for high reliability
- UL recognized, file no. E 63 532

Typical Applications

- DC motor control (e.g. for machine tools)
- AC motor soft starters
- Temperature control (e.g. for ovens, chemical processes)
- Professional light dimming (studios, theaters)

¹⁾ Also available in SKKT 57B configuration (case A 48)

²⁾ See the assembly instructions

³⁾ /20 E, /22 E max. 30 mA

SKKT 19 ... 105

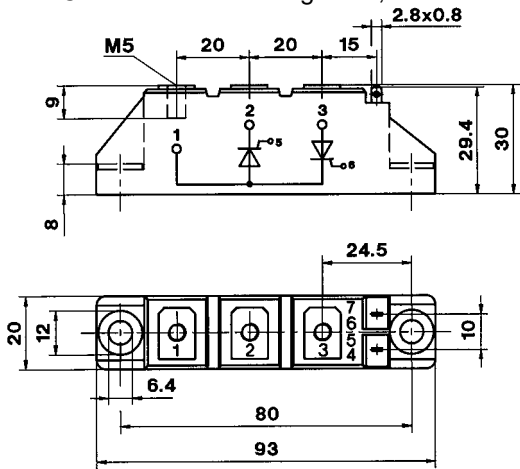
Case A 5

IEC 192-2: A 77 A

JEDEC: TO-240 AA

SEMIPACK® 1

UL recognized, file no. E 63 532



Dimensions in mm

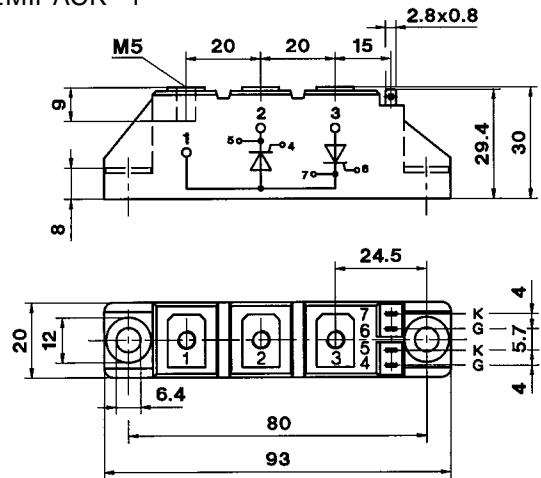
SKKT 20/ ... 106/

Case A 46

IEC 192-2: A 77 A

JEDEC: TO-240 AA

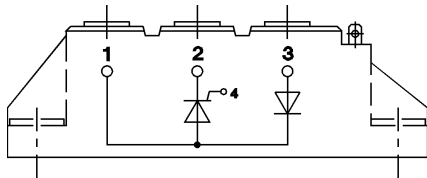
SEMIPACK® 1



Dimensions in mm

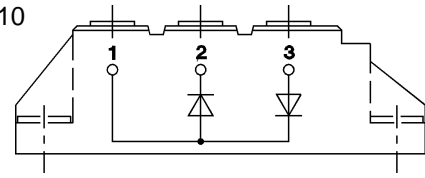
SKKH 26 ... 105

Case A 6



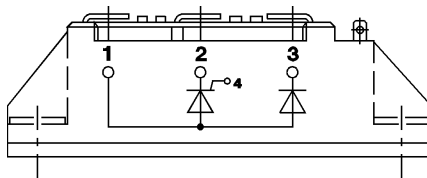
SKKD 26 ... 100

Case A 10



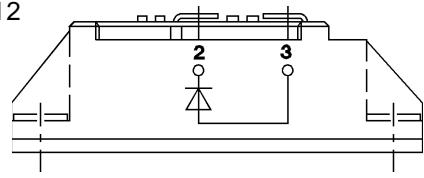
SKNH 56 ... 91

Case A 7



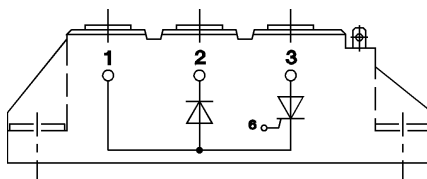
SKKE 81

Case A 12



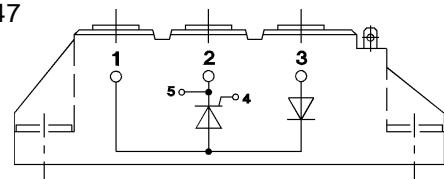
SKKL 56 ... 105

Case A 9



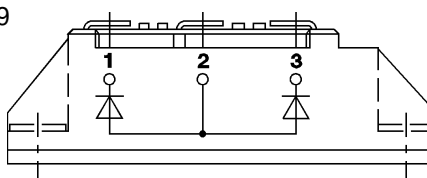
SKKH 27 ... 106

Case A 47



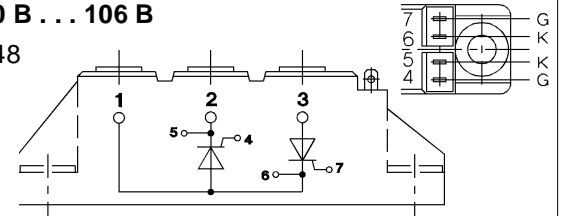
SKND 46 ... 81

Case A 19



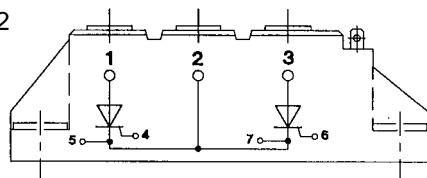
SKKT 20 B ... 106 B

Case A 48



SKMT 92

Case A 72



SKKL 42 ... 106

Case A 59

